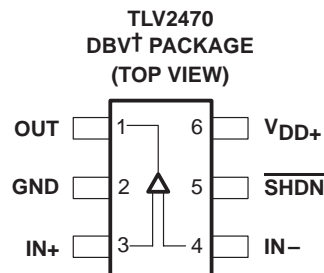


TLV2470, TLV2471, TLV2472, TLV2473, TLV2474, TLV2475, TLV247xA FAMILY OF 600- μ A/Ch 2.8-MHz RAIL-TO-RAIL INPUT/OUTPUT HIGH-DRIVE OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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- CMOS Rail-To-Rail Input/Output
- Input Bias Current . . . 2.5 pA
- Low Supply Current . . . 600 μ A/Channel
- Ultra-Low Power Shutdown Mode
 - $I_{DD}(SHDN)$. . . 350 nA/ch at 3 V
 - $I_{DD}(SHDN)$. . . 1000 nA/ch at 5 V
- Gain-Bandwidth Product . . . 2.8 MHz
- High Output Drive Capability
 - ± 10 mA at 180 mV
 - ± 35 mA at 500 mV
- Input Offset Voltage . . . 250 μ V (typ)
- Supply Voltage Range . . . 2.7 V to 6 V
- Ultra-Small Packaging
 - 5 or 6 Pin SOT-23 (TLV2470/1)
 - 8 or 10 Pin MSOP (TLV2472/3)



† This device is in the Product Preview stage of development. Please contact your local TI sales office for availability.

description

The TLV247x is a family of CMOS rail-to-rail input/output operational amplifiers that establishes a new performance point for supply current versus ac performance. These devices consume just 600 μ A/channel while offering 2.8 MHz of gain bandwidth product. Along with increased ac performance, the amplifier provides high output drive capability, solving a major shortcoming of older micropower operational amplifiers. The TLV247x can swing to within 180 mV of each supply rail while driving a 10-mA load. For non-RRO applications, the TLV247x can supply ± 35 mA at 500 mV off the rail. Both the inputs and outputs swing rail-to-rail for increased dynamic range in low-voltage applications. This performance makes the TLV247x family ideal for sensor interface, portable medical equipment, and other data acquisition circuits.

FAMILY PACKAGE TABLE

DEVICE	NUMBER OF CHANNELS	PACKAGE TYPES					SHUTDOWN	UNIVERSAL EVM BOARD
		PDIP	SOIC	SOT-23	TSSOP	MSOP		
TLV2470	1	8	8	6 [†]	—	—	Yes	UNIV-OPAMP-2
TLV2471	1	8	8	5 [†]	—	—	—	UNIV-OPAMP-1
TLV2472	2	8	8	—	—	8	—	UNIV-OPAMP-1
TLV2473	2	14	14	—	—	10	Yes	UNIV-OPAMP-2
TLV2474	4	14	14	—	14 [†]	—	—	—
TLV2475	4	16	16	—	16 [†]	—	Yes	—

[†] This device is in the Product Preview stage of development. Please contact your local TI sales office for availability.

A SELECTION OF SINGLE-SUPPLY OPERATIONAL AMPLIFIER PRODUCTS[§]

DEVICE	V _{DD} (V)	BW (MHz)	SLEW RATE (V/ μ s)	I _{DD} (per channel) (μ A)	RAIL-TO-RAIL
TLV247X	2.7 – 6.0	2.8	1.5	600	I/O
TLV245X	2.7 – 6.0	0.22	0.11	23	I/O
TLV246X	2.7 – 6.0	6.4	1.6	550	I/O
TLV277X	2.5 – 6.0	5.1	10.5	1000	O

[§] All specifications measured at 5 V.

TLV2470, TLV2471, TLV2472, TLV2473, TLV2474, TLV2475, TLV247xA
FAMILY OF 600- μ A/Ch 2.8-MHz RAIL-TO-RAIL INPUT/OUTPUT
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TLV2470 and TLV2471 AVAILABLE OPTIONS

T _A	PACKAGED DEVICES				CHIP FORM‡ (Y)
	SMALL OUTLINE (D)†	SOT-23		PLASTIC DIP (P)	
		(DBV)†	SYMBOL		
0°C to 70°C	TLV2470CD TLV2471CD	TLV2470CDBV§ TLV2471CDBV§	VAUC VAVC	TLV2470CP TLV2471CP	TLV2470Y TLV2471Y
-40°C to 125°C	TLV2470ID TLV2471ID	TLV2470IDBV§ TLV2471IDBV§	VAUI VAVI	TLV2470IP TLV2471IP	— —
	TLV2470AID TLV2471AID	— —	— —	TLV2470AIP TLV2471AIP	— —

† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2470CDR).

‡ Chip forms are tested at T_A = 25°C only.

§ This device is in the Product Preview stage of development. Please contact your local TI sales office for availability.

TLV2472 AND TLV2473 AVAILABLE OPTIONS

T _A	PACKAGED DEVICES						CHIP FORM‡ (Y)	
	SMALL OUTLINE (D)†	MSOP		MSOP		PLASTIC DIP (N)		PLASTIC DIP (P)
		(DGN)†	SYMBOL§	(DGQ)†	SYMBOL§			
0°C to 70°C	TLV2472CD TLV2473CD	TLV2472CDGN —	xxTIABU —	— TLV2473CDGQ	— xxTIABW	— TLV2473CN	TLV2472CP — TLV2473Y	
-40°C to 125°C	TLV2472ID TLV2473ID	TLV2472IDGN —	xxTIABV —	— TLV2473IDGQ	— xxTIABX	— TLV2473IN	TLV2472IP — —	
	TLV2472AID TLV2473AID	— —	— —	— —	— —	— TLV2473AIN	TLV2472AIP — —	

† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2472CDR).

‡ Chip forms are tested at T_A = 25°C only.

§ xx represents the device date code.

TLV2474 and TLV2475 AVAILABLE OPTIONS

T _A	PACKAGED DEVICES				CHIP FORM‡ (Y)
	SMALL OUTLINE (D)†	PLASTIC DIP (N)	TSSOP (PW)†	TSSOP (PWP)†	
0°C to 70°C	TLV2474CD TLV2475CD	TLV2474CN TLV2475CN	TLV2475CPW	TLV2474CPWP§	TLV2474Y TLV2475Y
-40°C to 125°C	TLV2474ID TLV2475ID	TLV2474IN TLV2475IN	TLV2475IPW	TLV2475CPWP§	— —
	TLV2474AID TLV2475AID	TLV2474AIN TLV2475AIN	TLV2475AIPW	TLV2475CPWP§	— —

† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2474CDR).

‡ Chip forms are tested at T_A = 25°C only.

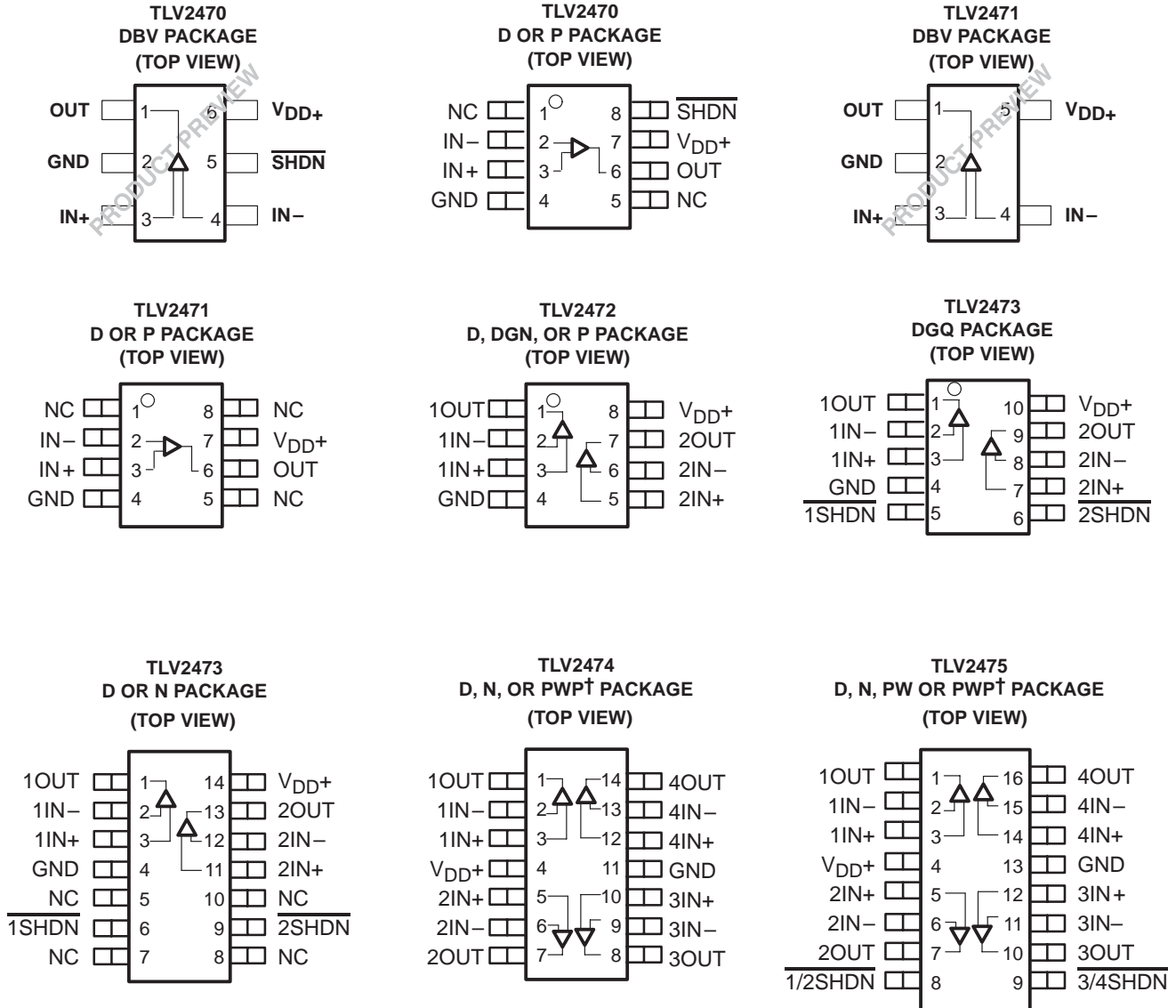
§ This device is in the Product Preview stage of development. Please contact your local TI sales office for availability.



TLV2470, TLV2471, TLV2472, TLV2473, TLV2474, TLV2475, TLV247xA
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TLV247x PACKAGE PINOUTS



NC – No internal connection

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description (continued)

Three members of the family (TLV2470/3/5) offer a shutdown terminal for conserving battery life in portable applications. During shutdown, the outputs are placed in a high-impedance state and the amplifier consumes only 350 nA/channel. The family is fully specified at 3 V and 5 V across an expanded industrial temperature range (-40°C to 125°C). The singles and duals are available in the SOT23 and MSOP packages, while the quads are available in TSSOP. The TLV2470 offers an amplifier with shutdown functionality all in a 6-pin SOT23 package, making it perfect for high density power-sensitive circuits.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{DD} (see Note 1)	7 V
Differential input voltage, V_{ID}	$\pm V_{DD}$
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	-40°C to 125°C
Maximum junction temperature, T_J	150°C
Storage temperature range, T_{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE: All voltage values, except differential voltages, are with respect to V_{DD-} .

DISSIPATION RATING TABLE

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W)	$T_A \leq 25^\circ\text{C}$ POWER RATING
D (8)	38.3	176	710 mW
D (14)	26.9	122.3	1022 mW
D (16)	25.7	114.7	1090 mW
DBV (5)	55	324.1	385 mW
DBV (6)	55	294.3	425 mW
DGN (8)	4.7	52.7	2.37 W
DGQ (10)	4.7	52.3	2.39 W
N (14, 16)	32	78	1600 mW
P (8)	41	104	1200 mW
PW (16)	28.7	161.4	720 mW
PWP (14)	2.07	30.7	4.07 W
PWP (16)	2.07	29.7	4.21 W

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{DD}	Single supply	2.7	6	V
	Split supply	± 1.35	± 3	
Common-mode input voltage range, V_{ICR}		V_{DD-}	V_{DD+}	V
Operating free-air temperature, T_A	C-suffix	0	70	°C
	I-suffix	-40	125	



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electrical characteristics at specified free-air temperature, $V_{DD} = 3$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A †	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	TLV247x		25°C		250	2200	μ V
				Full range			2400	
		TLV247xA		25°C		250	1600	
				Full range			1800	
α_{VIO}	Temperature coefficient of input offset voltage		$V_{DD} = \pm 1.5$ V $V_{IC} = 0$, $V_O = 0$, $R_S = 50$ Ω	25°C		0.4		μ V/°C
I_{IO}	Input offset current			25°C		1.5	50	pA
		TLV247xC		Full range			100	pA
		TLV247xl		Full range			300	pA
I_{IB}	Input bias current			25°C		2	50	pA
		TLV247xC		Full range			100	pA
		TLV247xl		Full range			300	pA
V_{ICR}	Common-mode input voltage range	CMRR > 70 dB	$R_S = 50$ Ω	25°C		-0.2 to 3.2		V
		CMRR > 52 dB	$R_S = 50$ Ω	Full range		-0.2 to 3.2		
V_{OH}	High-level output voltage	$V_{IC} = 1.5$ V		25°C		2.85	2.94	V
				25°C		2.6	2.74	
V_{OL}	Low-level output voltage	$V_{IC} = 1.5$ V		25°C		0.07	0.15	V
				25°C		0.2	0.35	
I_{OS}	Short-circuit output current			25°C		30	mA	
								Full range
				25°C		62		
								TLV247xC
				TLV247xl	Full range			59
				25°C		30		
								Full range
				25°C		62		
TLV247xC	Full range		60					
TLV247xl	Full range		59					
I_O	Output current	$V_O = 0.5$ V from rail		25°C		± 22		mA
A_{VD}	Large-signal differential voltage amplification	$V_O(PP) = 1$ V,	$R_L = 10$ k Ω	25°C		90	116	dB
				Full range		88		
$r_{i(d)}$	Differential input resistance			25°C		10^{12}		Ω
C_{IC}	Common-mode input capacitance	$f = 10$ kHz		25°C		19.3		pF
z_O	Closed-loop output impedance	$f = 10$ kHz,	$A_V = 10$	25°C		2		Ω

† Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

‡ Depending on package dissipation rating



TLV2470, TLV2471, TLV2472, TLV2473, TLV2474, TLV2475, TLV247xA
FAMILY OF 600- μ A/Ch 2.8-MHz RAIL-TO-RAIL INPUT/OUTPUT
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electrical characteristics at specified free-air temperature, $V_{DD} = 3$ V (unless otherwise noted)
(continued)

PARAMETER		TEST CONDITIONS		T_A †	MIN	TYP	MAX	UNIT
CMRR	Common-mode rejection ratio	$V_{IC} = 0$ to 3 V, $R_S = 50 \Omega$	TLV247xC	25°C	61	78	dB	
			TLV247xI	Full range	59			
		$V_{IC} = -0.2$ to 3.2 V, $R_S = 50 \Omega$, Outside of rails	TLV247xC	25°C	62	78		
			TLV247xI	Full range	60	59		
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	$V_{DD} = 2.7$ V to 6 V, No load	$V_{IC} = V_{DD}/2$,	25°C	74	90	dB	
			Full range	66				
		$V_{DD} = 3$ V to 5 V, No load	$V_{IC} = V_{DD}/2$,	25°C	77	92		
			Full range	68				
I_{DD}	Supply current (per channel)	$V_O = 1.5$ V, No load		25°C		550	750	μ A
			Full range				800	
$V_{(ON)}$	Turnon voltage level	Relative to GND		25°C		1.03		V
$V_{(OFF)}$	Turnoff voltage level	Relative to GND		25°C		0.81		V
$I_{DD(SHDN)}$	Supply current in shutdown mode (TLV2470, TLV2473, TLV2475) (per channel)	$\overline{SHDN} = < 1.45$ V		25°C		350	1500	nA
			TLV247xC	Full range			2000	
			TLV247xI	Full range				

† Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

operating characteristics at specified free-air temperature, $V_{DD} = 3$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A †	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_{O(PP)} = 0.8$ V, $R_L = 10$ k Ω	$C_L = 150$ pF,	25°C	1.1	1.4	V/ μ s	
				Full range	0.6			
V_n	Equivalent input noise voltage	$f = 100$ Hz		25°C		28	nV/ \sqrt{Hz}	
			$f = 1$ kHz	25°C		15		
I_n	Equivalent input noise current	$f = 1$ kHz		25°C		0.405	pA/ \sqrt{Hz}	
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 2$ V, $R_L = 10$ k Ω , $f = 1$ kHz	$A_V = 1$	25°C		0.02%		
			$A_V = 10$			0.1%		
			$A_V = 100$			0.5%		
$t_{(on)}$	Amplifier turnon time	$R_L = OPEN$ ‡		25°C		5	μ s	
$t_{(off)}$	Amplifier turnoff time		25°C		250	ns		
	Gain-bandwidth product	$f = 10$ kHz,	$R_L = 600 \Omega$	25°C		2.8	MHz	
t_s	Settling time	$V_{(STEP)PP} = 2$ V, $A_V = -1$, $C_L = 10$ pF, $R_L = 10$ k Ω	0.1%	25°C		1.5	μ s	
			0.01%			3.9		
		$V_{(STEP)PP} = 2$ V, $A_V = -1$, $C_L = 56$ pF, $R_L = 10$ k Ω	0.1%			1.6		
			0.01%			4		
ϕ_m	Phase margin	$R_L = 10$ k Ω ,	$C_L = 1000$ pF	25°C		61°		
	Gain margin	$R_L = 10$ k Ω ,	$C_L = 1000$ pF	25°C		15	dB	

† Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

‡ Depending on package dissipation rating



TLV2470, TLV2471, TLV2472, TLV2473, TLV2474, TLV2475, TLV247xA
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electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A^\dagger	MIN	TYP	MAX	UNIT	
V_{IO}	Input offset voltage	TLV247x	$V_{DD} = \pm 2.5\text{ V}$ $V_{IC} = 0, V_O = 0,$ $R_S = 50\ \Omega$	25°C		250	2200	μV	
				Full range			2400		
		TLV247xA		25°C		250	1600		
				Full range			2000		
α_{VIO}	Temperature coefficient of input offset voltage			25°C		0.4		$\mu\text{V}/^\circ\text{C}$	
I_{IO}	Input offset current			25°C		1.7	50	pA	
			TLV247xC	Full range			100	pA	
			TLV247xl	Full range			300	pA	
I_{IB}	Input bias current			25°C		2.5	50	pA	
			TLV247xC	Full range			100		
			TLV247xl	Full range			300		
V_{ICR}	Common-mode input voltage range	CMRR > 70 dB	$R_S = 50\ \Omega$	25°C		-0.2	5.2	V	
		CMRR > 52 dB	$R_S = 50\ \Omega$	Full range		-0.2	5.2		
V_{OH}	High-level output voltage	$V_{IC} = 2.5\text{ V}$		$I_{OH} = -2.5\text{ mA}$	25°C	4.85	4.96	V	
					Full range		4.8		
				$I_{OH} = -10\text{ mA}$	25°C	4.72	4.82		
					Full range		4.65		
V_{OL}	Low-level output voltage	$V_{IC} = 2.5\text{ V}$		$I_{OL} = 2.5\text{ mA}$	25°C		0.07	0.15	V
					Full range			0.2	
				$I_{OL} = 10\text{ mA}$	25°C		0.178	0.28	
					Full range			0.35	
I_{OS}	Short-circuit output current			Sourcing	25°C		90	mA	
					Full range		60		
				Sourcing, Outside of rails \ddagger	25°C		63		
					TLV247xC	Full range			61
				TLV247xl	Full range		58		
				Sinking	25°C		110		
					Full range		60		
				Sinking, Outside of rails \ddagger	25°C		63		
TLV247xC	Full range		61						
TLV247xl	Full range		58						
I_O	Output current	$V_O = 0.5\text{ V}$ from rail		25°C		± 35		mA	
A_{VD}	Large-signal differential voltage amplification	$V_{O(PP)} = 3\text{ V},$	$R_L = 10\text{ k}\Omega$	25°C		92	120	dB	
				Full range		91			
$r_{i(d)}$	Differential input resistance			25°C		10^{12}		Ω	
C_{IC}	Common-mode input capacitance	$f = 10\text{ kHz}$		25°C		18.9		pF	
z_o	Closed-loop output impedance	$f = 10\text{ kHz},$	$A_V = 10$	25°C		1.8		Ω	

\dagger Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

\ddagger Depending on package dissipation rating



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electrical characteristics at specified free-air temperature, $V_{DD} = 5$ V (unless otherwise noted)
(continued)

PARAMETER		TEST CONDITIONS		T_A †	MIN	TYP	MAX	UNIT	
CMRR	Common-mode rejection ratio	$V_{IC} = 0$ to 5 V, $R_S = 50 \Omega$	TLV247xC	25°C	64	84		dB	
			TLV247xI	Full range	63				
		$V_{IC} = -0.2$ to 5.2 V, $R_S = 50 \Omega$, Outside of rails	TLV247xC	25°C	63	82			
			TLV247xI	Full range	58				
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	$V_{DD} = 2.7$ V to 6 V, No load	$V_{IC} = V_{DD}/2$,	25°C	74	90		dB	
			Full range	66					
		$V_{DD} = 3$ V to 5 V, No load	$V_{IC} = V_{DD}/2$,	25°C	77	92			
			Full range	66					
I_{DD}	Supply current (per channel)	$V_O = 2.5$ V, No load		25°C		600	900	μ A	
			Full range				1000		
$V_{(ON)}$	Turnon voltage level	Relative to GND		25°C		1.38		V	
$V_{(OFF)}$	Turnoff voltage level	Relative to GND		25°C		1.3		V	
$I_{DD}(SHDN)$	Supply current in shutdown mode (TLV2470, TLV2473, TLV2475) (per channel)	$SHDN = < 1.45$ V		25°C		1000	2500	nA	
			TLV247xC	Full range			3000		
			TLV247xI	Full range					6000

† Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

operating characteristics at specified free-air temperature, $V_{DD} = 5$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A †	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_{O(PP)} = 2$ V, $R_L = 10$ k Ω	$C_L = 150$ pF,	25°C	1.1	1.5		V/ μ s
				Full range	0.7			
V_n	Equivalent input noise voltage	$f = 100$ Hz		25°C		28		nV/ \sqrt{Hz}
			$f = 1$ kHz	25°C		15		
I_n	Equivalent input noise current	$f = 1$ kHz		25°C		0.39		pA/ \sqrt{Hz}
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 4$ V, $R_L = 10$ k Ω , $f = 1$ kHz	$A_V = 1$	25°C		0.01%		
			$A_V = 10$			0.05%		
			$A_V = 100$			0.3%		
$t_{(on)}$	Amplifier turnon time	$R_L = OPEN$ ‡		25°C		5		μ s
$t_{(off)}$	Amplifier turnoff time		25°C		250		ns	
	Gain-bandwidth product	$f = 10$ kHz,	$R_L = 600 \Omega$	25°C		2.8		MHz
t_s	Settling time	$V_{(STEP)PP} = 2$ V, $A_V = -1$, $C_L = 10$ pF, $R_L = 10$ k Ω	0.1%	25°C		1.8		μ s
			0.01%			3.3		
		$V_{(STEP)PP} = 2$ V, $A_V = -1$, $C_L = 56$ pF, $R_L = 10$ k Ω	0.1%			1.7		
			0.01%			3		
ϕ_m	Phase margin	$R_L = 10$ k Ω ,	$C_L = 1000$ pF	25°C		68°		
	Gain margin	$R_L = 10$ k Ω ,	$C_L = 1000$ pF	25°C		23		dB

† Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

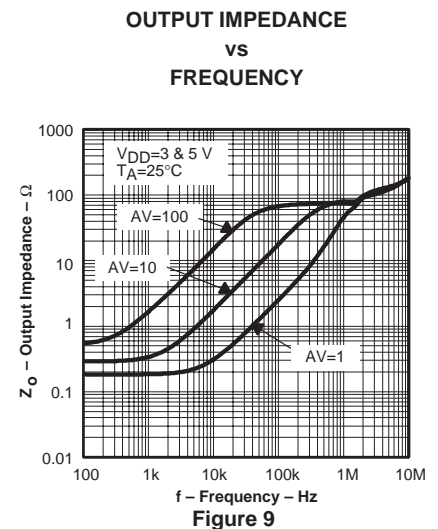
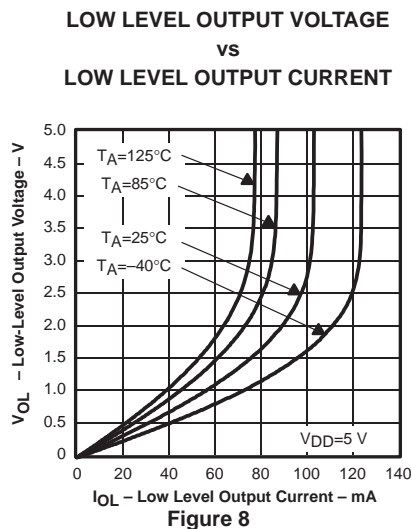
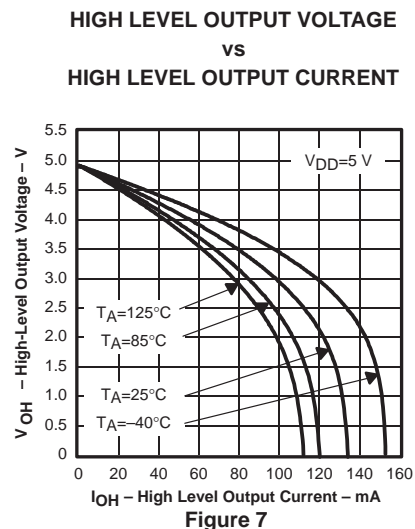
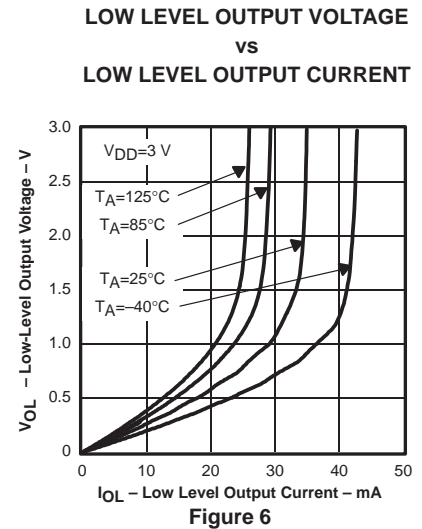
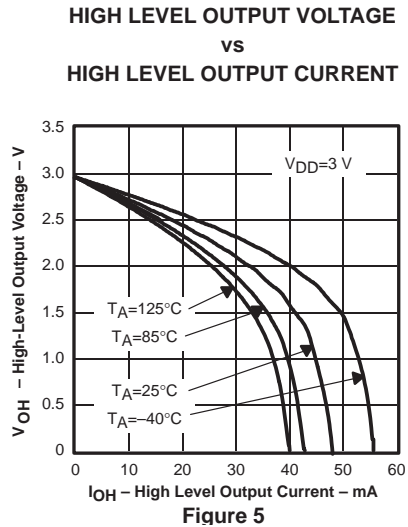
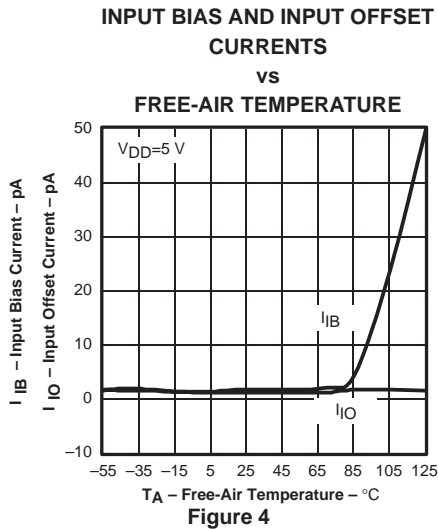
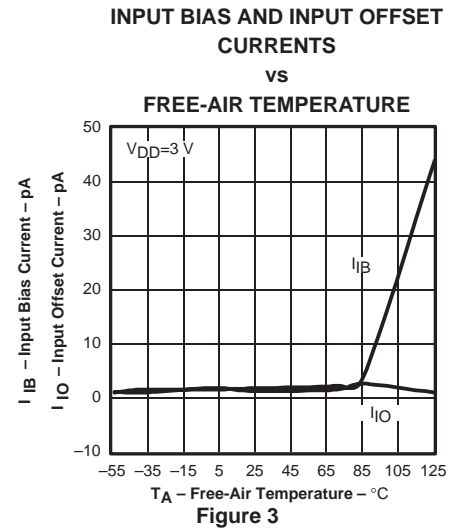
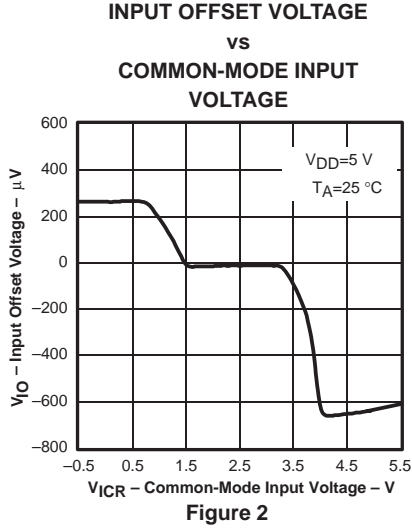
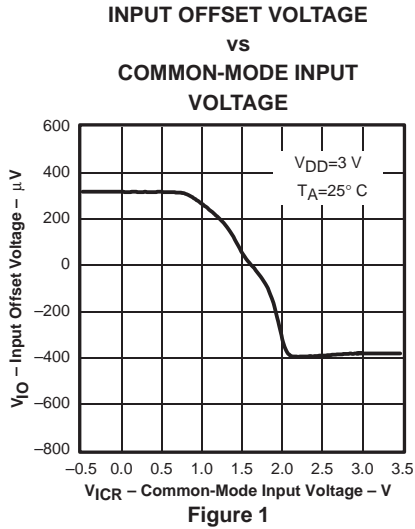
‡ Disable and enable time are defined as the interval between application of logic signal to SHDN and the point at which the supply current has reached half its final value.



TLV2470, TLV2471, TLV2472, TLV2473, TLV2474, TLV2475, TLV247xA FAMILY OF 600- μ A/Ch 2.8-MHz RAIL-TO-RAIL INPUT/OUTPUT HIGH-DRIVE OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

SUPPLY CURRENT
vs
SUPPLY VOLTAGE

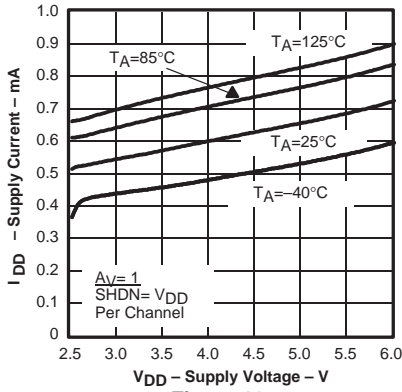


Figure 10

POWER SUPPLY REJECTION RATIO
vs
FREQUENCY

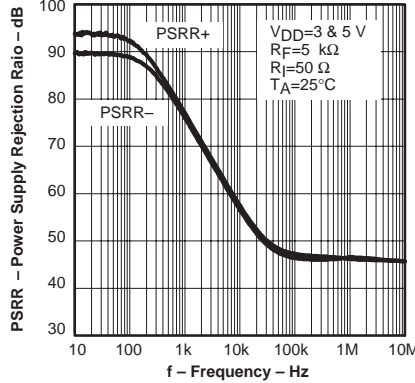


Figure 11

COMMON-MODE REJECTION RATIO
vs
FREQUENCY

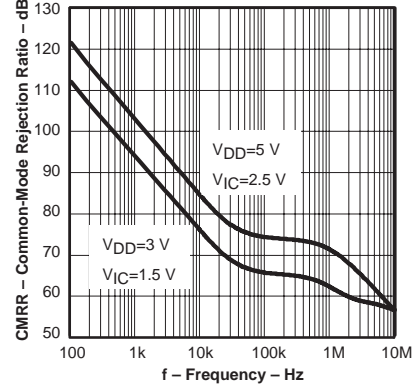


Figure 12

EQUIVALENT NOISE VOLTAGE
vs
FREQUENCY

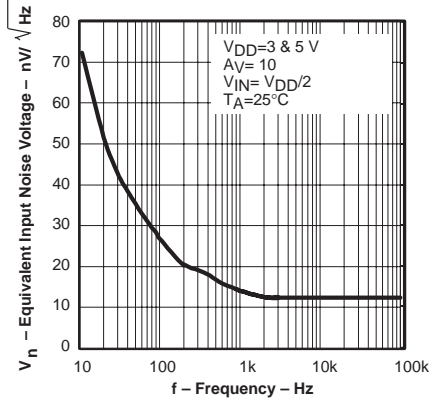


Figure 13

MAXIMUM PEAK-TO-PEAK
OUTPUT VOLTAGE

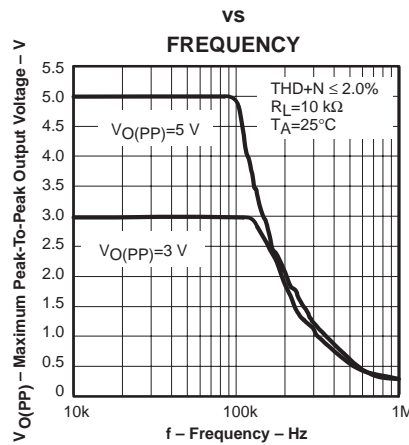


Figure 14

MAXIMUM PEAK-TO-PEAK
OUTPUT VOLTAGE

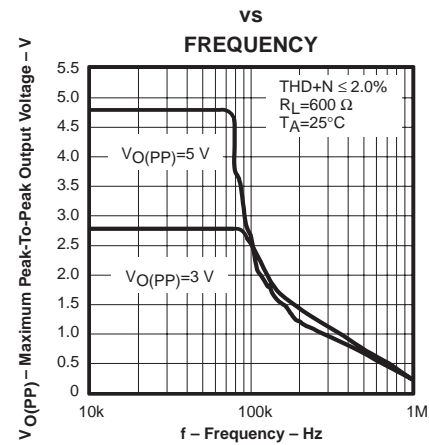


Figure 15

DIFFERENTIAL VOLTAGE GAIN AND PHASE
vs
FREQUENCY

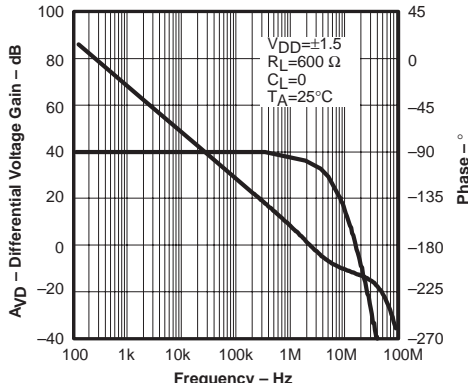


Figure 16

DIFFERENTIAL VOLTAGE GAIN AND PHASE
vs
FREQUENCY

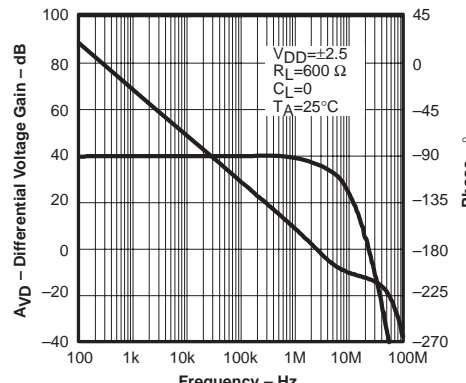


Figure 17

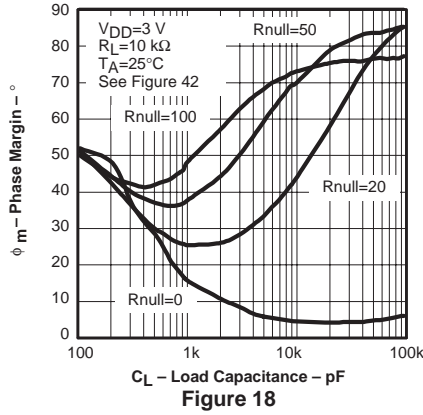


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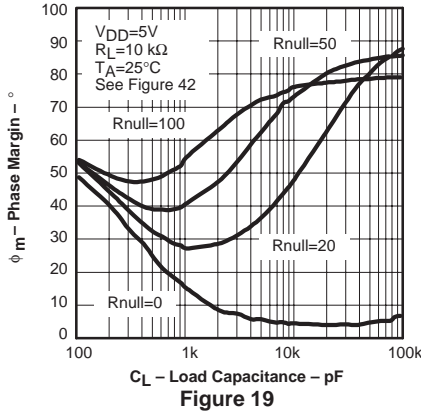
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TYPICAL CHARACTERISTICS

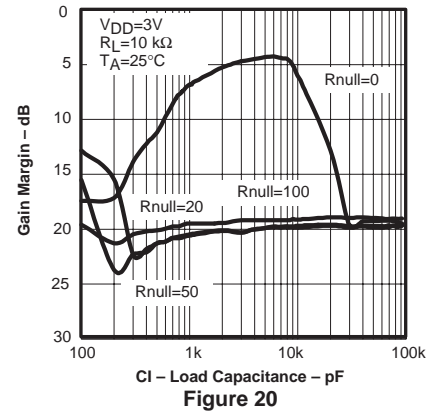
PHASE MARGIN
 vs
 LOAD CAPACITANCE



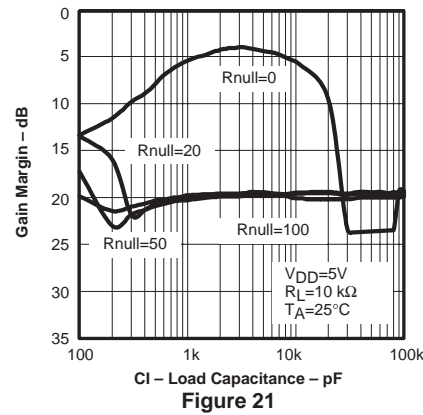
PHASE MARGIN
 vs
 LOAD CAPACITANCE



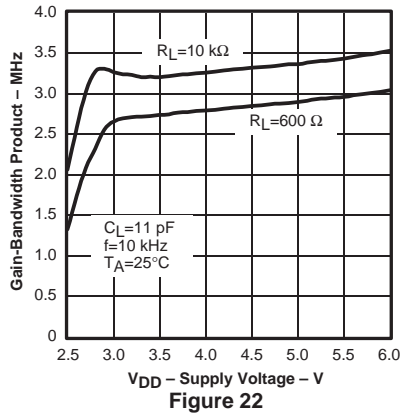
GAIN MARGIN
 vs
 LOAD CAPACITANCE



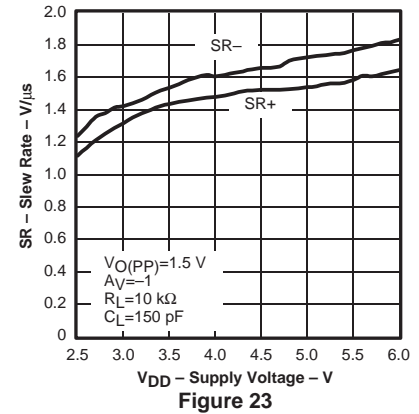
GAIN MARGIN
 vs
 LOAD CAPACITANCE



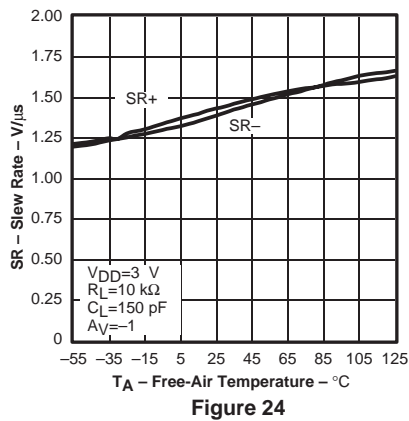
GAIN BANDWIDTH PRODUCT
 vs
 SUPPLY VOLTAGE



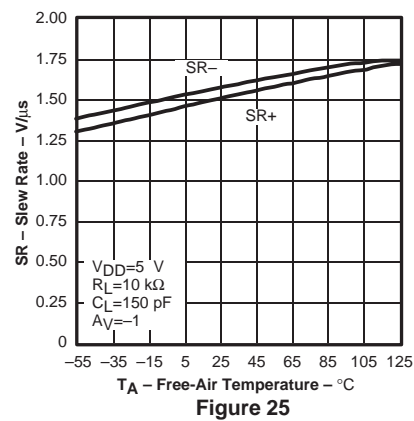
SLEW RATE
 vs
 SUPPLY VOLTAGE



SLEW RATE
 vs
 FREE-AIR TEMPERATURE



SLEW RATE
 vs
 FREE-AIR TEMPERATURE

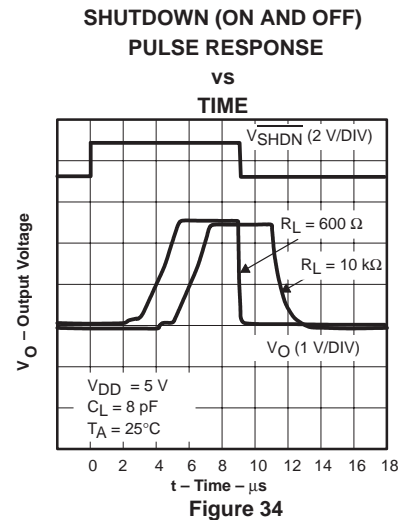
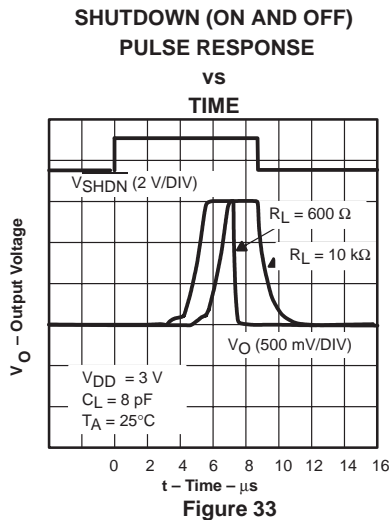
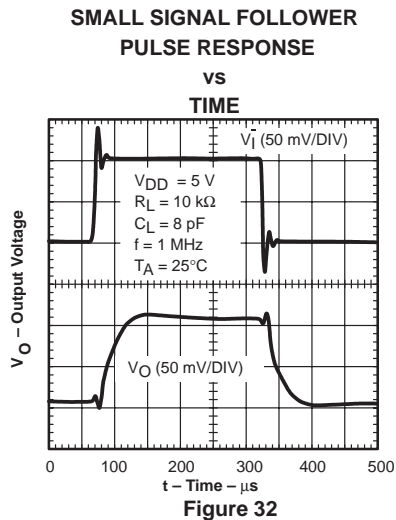
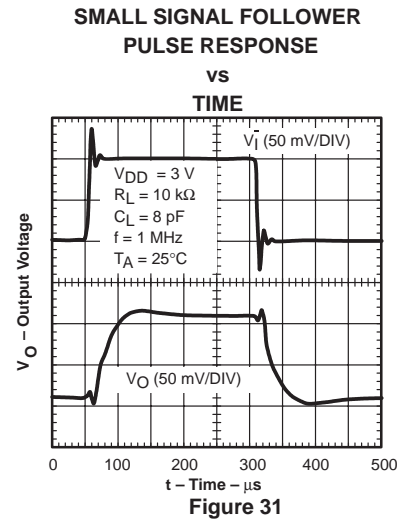
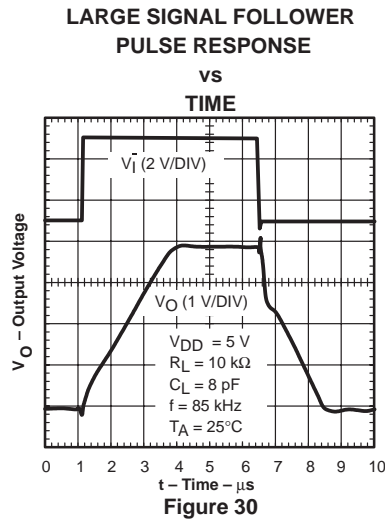
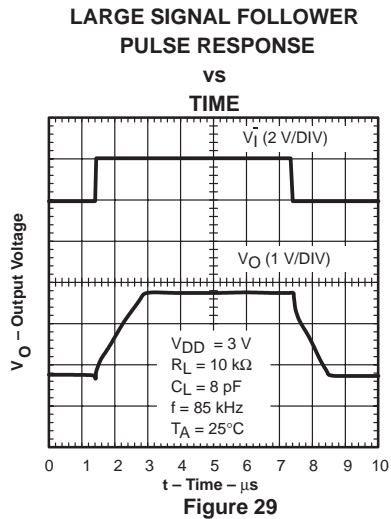
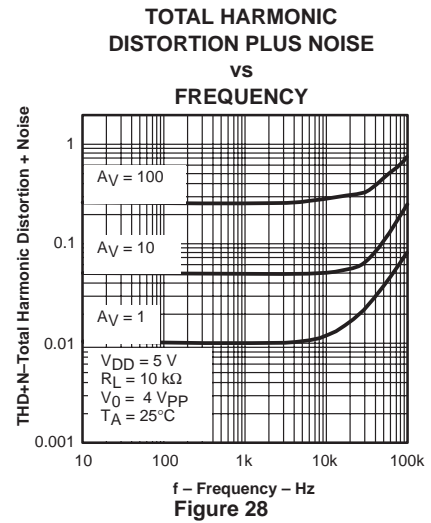
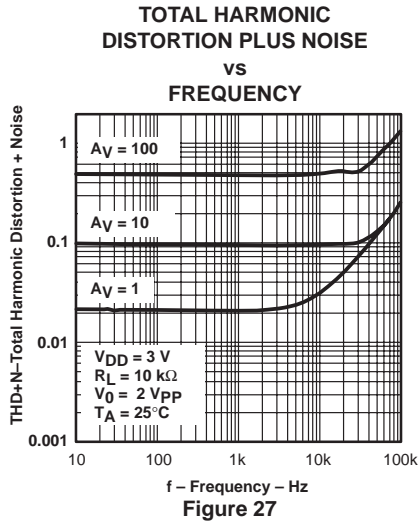
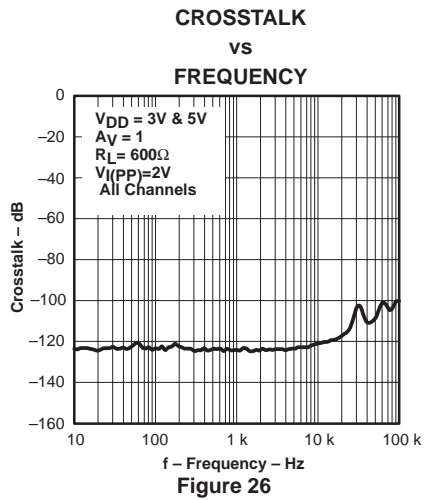


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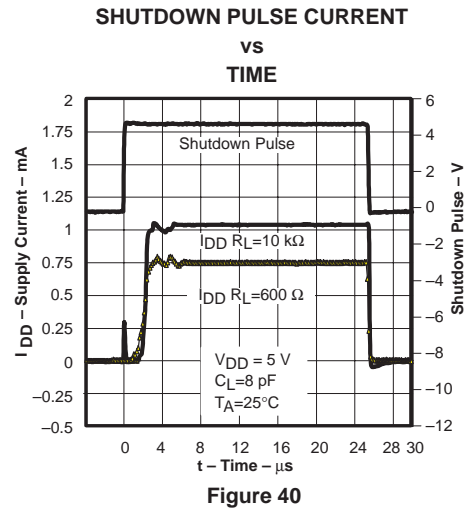
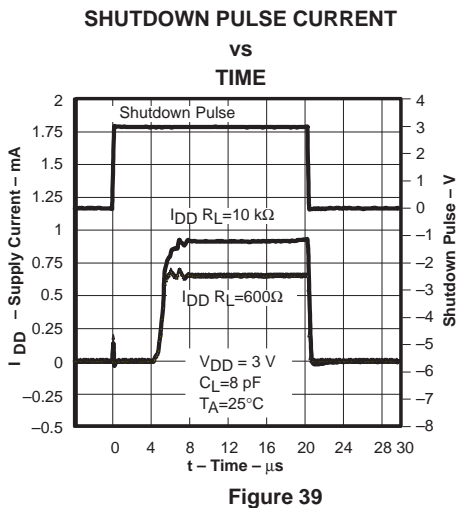
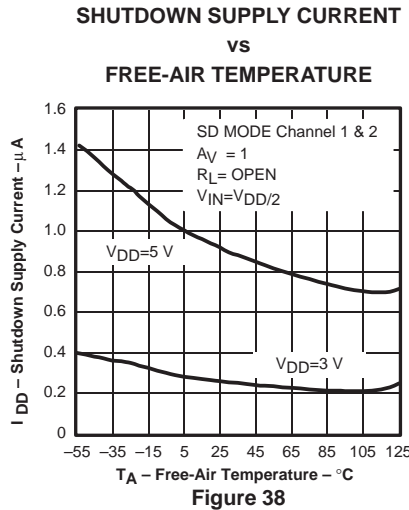
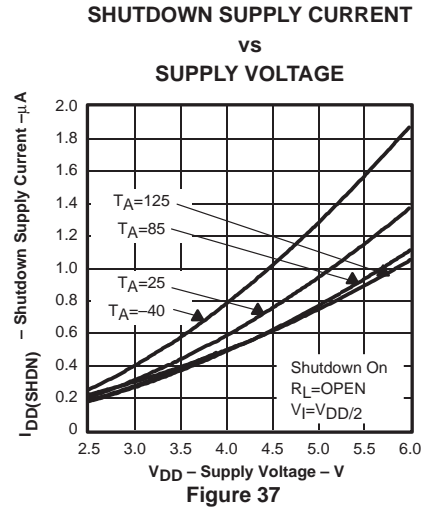
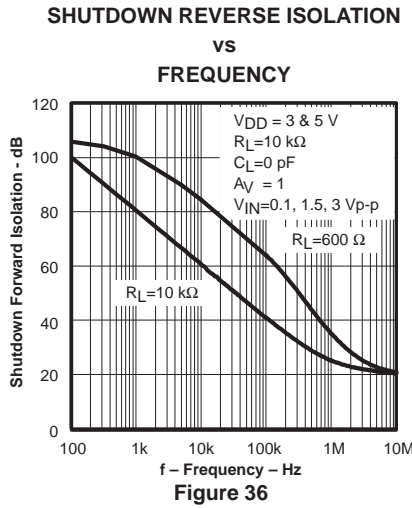
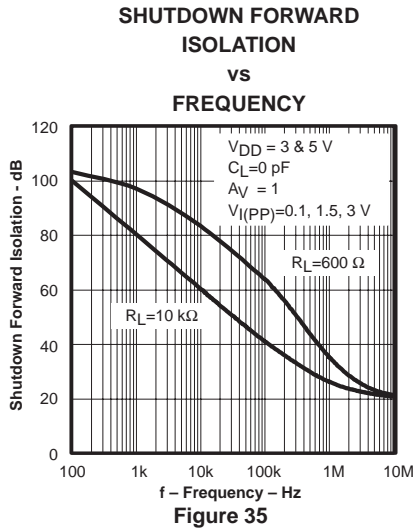
TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS



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PARAMETER MEASUREMENT INFORMATION

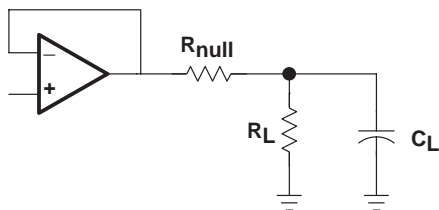


Figure 41

APPLICATION INFORMATION

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 42. A minimum value of 20 Ω should work well for most applications.

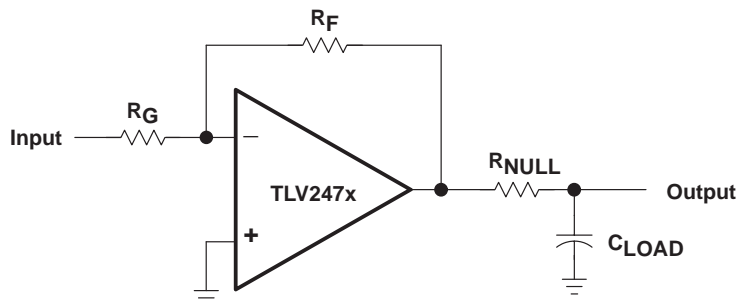


Figure 42. Driving a Capacitive Load

APPLICATION INFORMATION

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

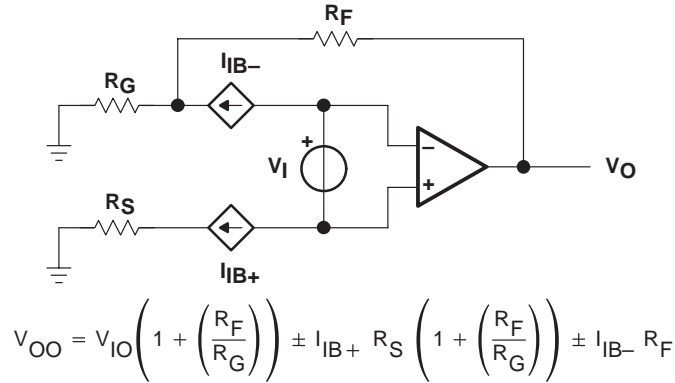


Figure 43. Output Offset Voltage Model

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 44).

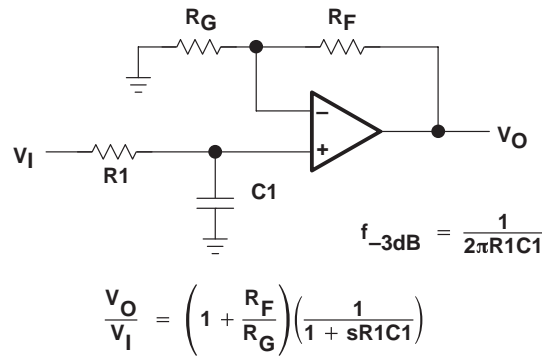


Figure 44. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

APPLICATION INFORMATION

general configurations (continued)

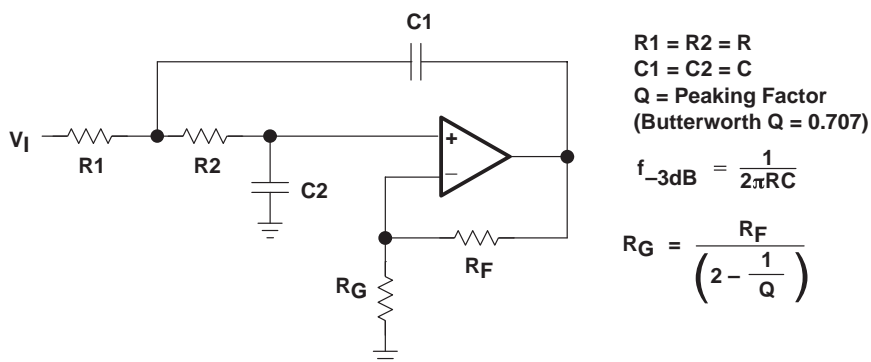


Figure 45. 2-Pole Low-Pass Sallen-Key Filter

shutdown function

Three members of the TLV247x family (TLV2470/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 350 nA/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown. The shutdown terminal threshold is always referenced to $V_{DD}/2$. Therefore, when operating the device with split supply voltages (e.g. ± 2.5 V), the shutdown terminal needs to be pulled to V_{DD-} (not GND) to disable the operational amplifier.

The amplifier's output with a shutdown pulse is shown in Figures 33 and 34. The amplifier is powered with a single 5-V supply and configured as a noninverting configuration with a gain of 5. The amplifier turnon and turnoff times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad are listed in the data tables.

Figures 35 and 36 show the amplifier's forward and reverse isolation in shutdown. The operational amplifier is powered by ± 1.35 -V supplies and configured as a voltage follower ($A_V = 1$). The isolation performance is plotted across frequency using 0.1- V_{PP} , 1.5- V_{PP} , and 2.5- V_{PP} input signals. During normal operation, the amplifier would not be able to handle a 2.5- V_{PP} input signal with a supply voltage of ± 1.35 V since it exceeds the common-mode input voltage range (V_{ICR}). However, this curve illustrates that the amplifier remains in shutdown even under a worst case scenario.

APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV247x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes – It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling – Use a 6.8- μ F tantalum capacitor in parallel with a 0.1- μ F ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- μ F ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μ F capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets – Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements – Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components – Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

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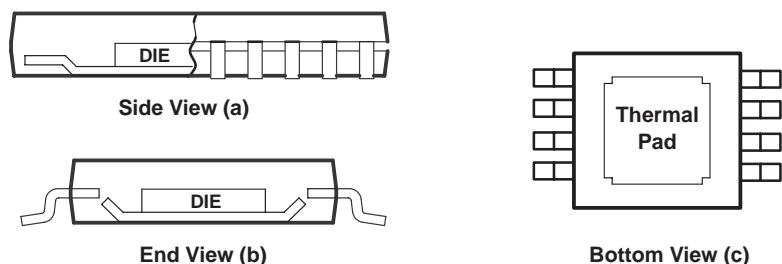
APPLICATION INFORMATION

general PowerPAD™ design considerations

The TLV247x is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted [see Figure 46(a) and Figure 46(b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 46(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the, heretofore, awkward mechanical methods of heatsinking.



NOTE A. The thermal pad is electrically isolated from all terminals in the package.

Figure 46. Views of Thermally Enhanced DGN Package

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

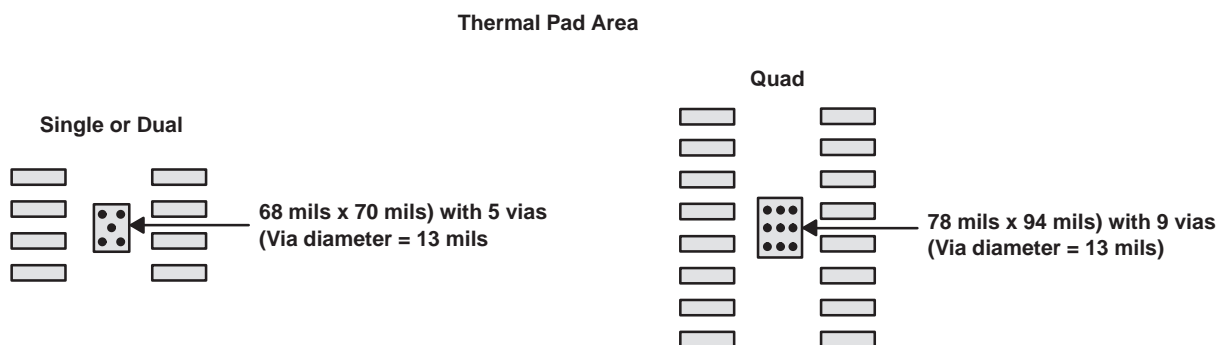


Figure 47. PowerPAD PCB Etch and Via Pattern

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APPLICATION INFORMATION

general PowerPAD design considerations (continued)

1. Prepare the PCB with a top side etch pattern as shown in Figure 47. There should be etch for the leads as well as etch for the thermal pad.
2. Place five holes (dual) or nine holes (quad) in the area of the thermal pad. These holes should be 13 mils in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.
3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the TLV247x IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
4. Connect all holes to the internal ground plane.
5. When connecting these holes to the ground plane, **do not** use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the TLV247x PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes (dual) or nine holes (quad) exposed. The bottom-side solder mask should cover the five or nine holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
8. With these preparatory steps in place, the TLV247x IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

For a given θ_{JA} , the maximum power dissipation is shown in Figure 48 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

P_D = Maximum power dissipation of TLV247x IC (watts)

T_{MAX} = Absolute maximum junction temperature (150°C)

T_A = Free-ambient air temperature (°C)

θ_{JA} = $\theta_{JC} + \theta_{CA}$

θ_{JC} = Thermal coefficient from junction to case

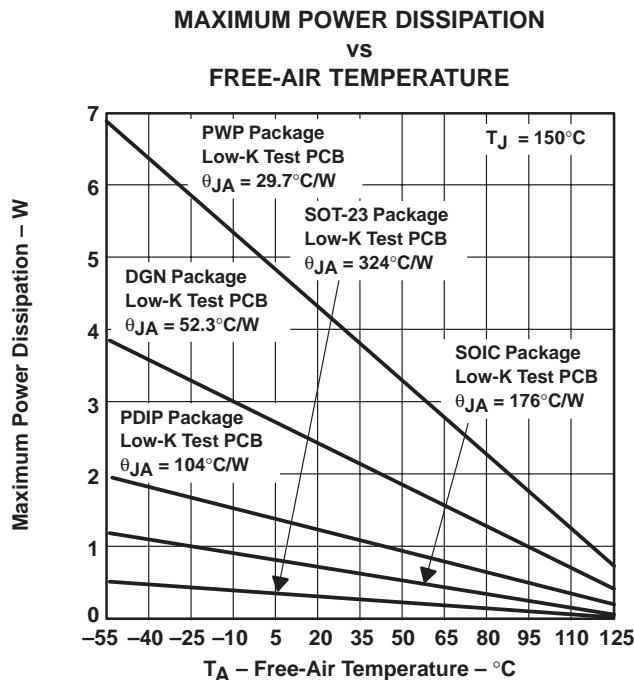
θ_{CA} = Thermal coefficient from case to ambient air (°C/W)

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APPLICATION INFORMATION

general PowerPAD design considerations (continued)



NOTE A. Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 48. Maximum Power Dissipation vs Free-Air Temperature

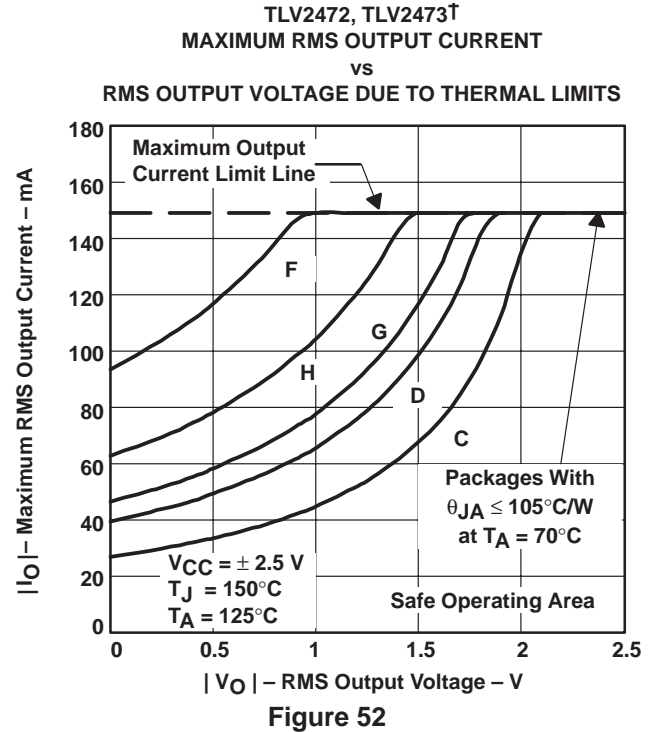
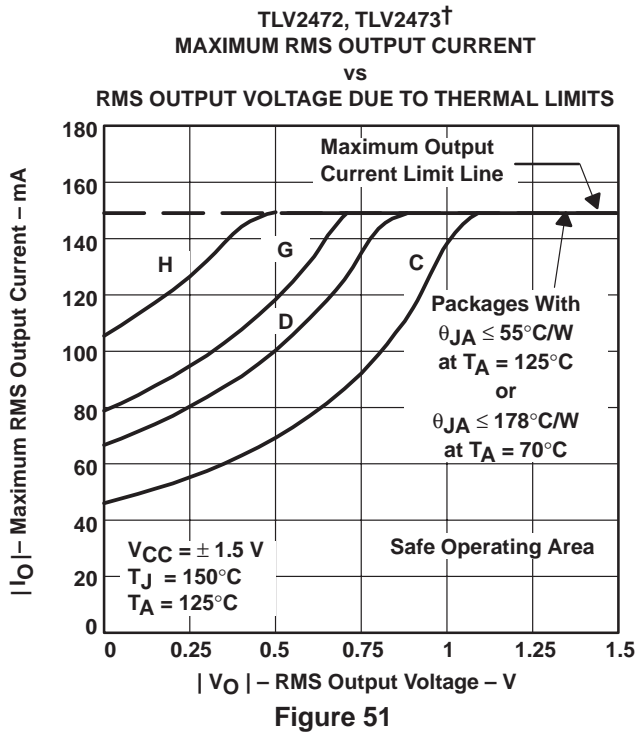
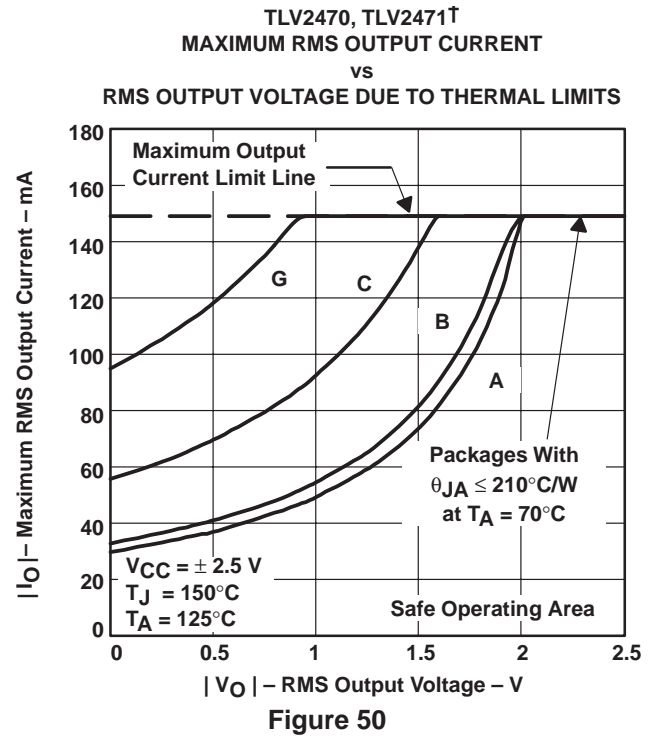
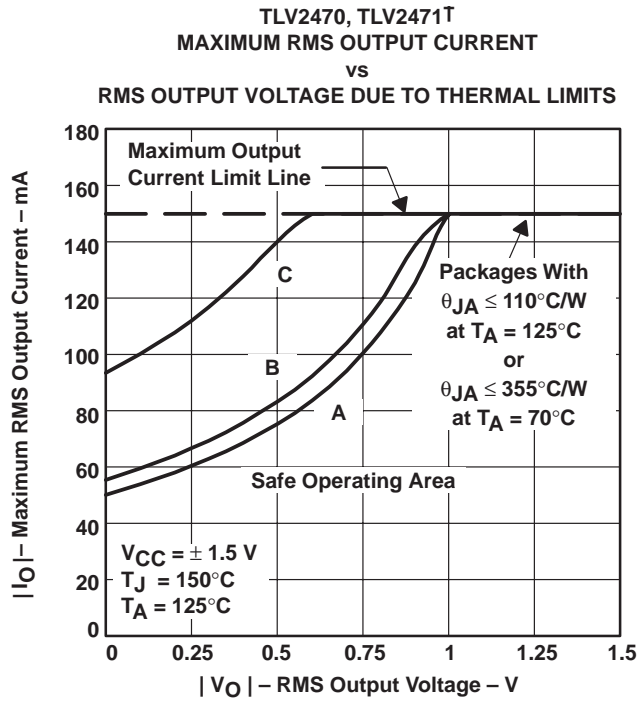
The next consideration is the package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially multi-amplifier devices. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents. Figure 49 to Figure 54 show this effect, along with the quiescent heat, with an ambient air temperature of 70°C and 125°C. When using $V_{DD} = 3$ V, there is generally not a heat problem with an ambient air temperature of 70°C. But, when using $V_{DD} = 5$ V, the packages are severely limited in the amount of heat it can dissipate. The other key factor when looking at these graphs is how the devices are mounted on the PCB. The PowerPAD devices are extremely useful for heat dissipation. But, the device should always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. For the dual or quad amplifier packages, the sum of the RMS output currents and voltages should be used to choose the proper package.

TLV2470, TLV2471, TLV2472, TLV2473, TLV2474, TLV2475, TLV247xA
 FAMILY OF 600- μ A/Ch 2.8-MHz RAIL-TO-RAIL INPUT/OUTPUT
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APPLICATION INFORMATION

general PowerPAD design considerations (continued)



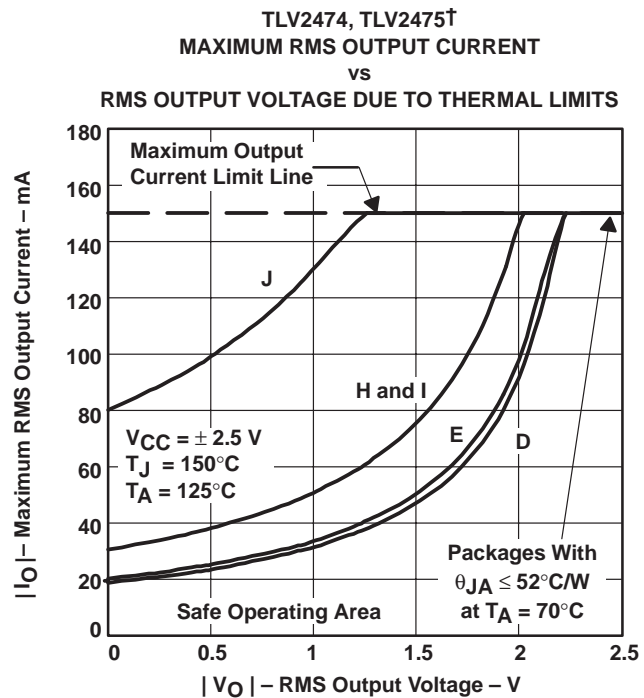
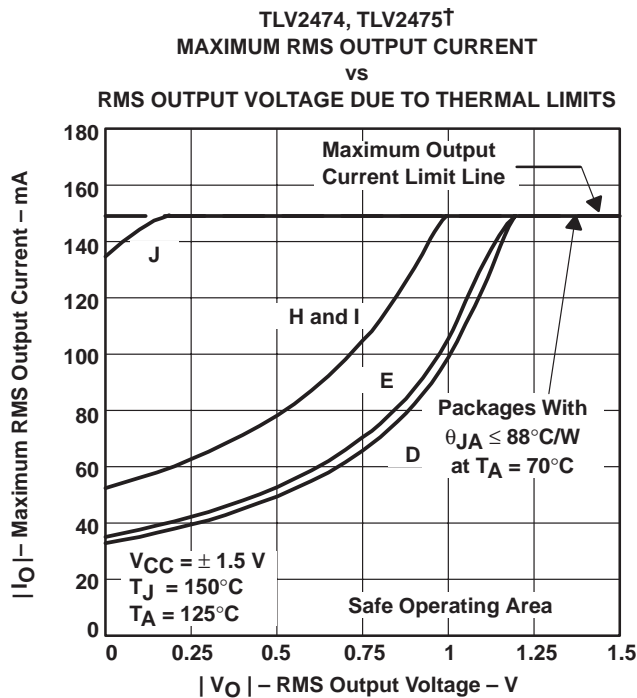
† A – SOT23(5); B – SOT23 (6); C – SOIC (8); D – SOIC (14); E – SOIC (16); F – MSOP PP (8); G – PDIP (8); H – PDIP (14); I – PDIP (16); J – TSSOP PP (14/16)

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APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*[™], the model generation software used with Microsim *PSpice*[™]. The Boyle macromodel (see Note 1) and subcircuit in Figure 2 are generated using the TLV247x typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 1: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers," *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

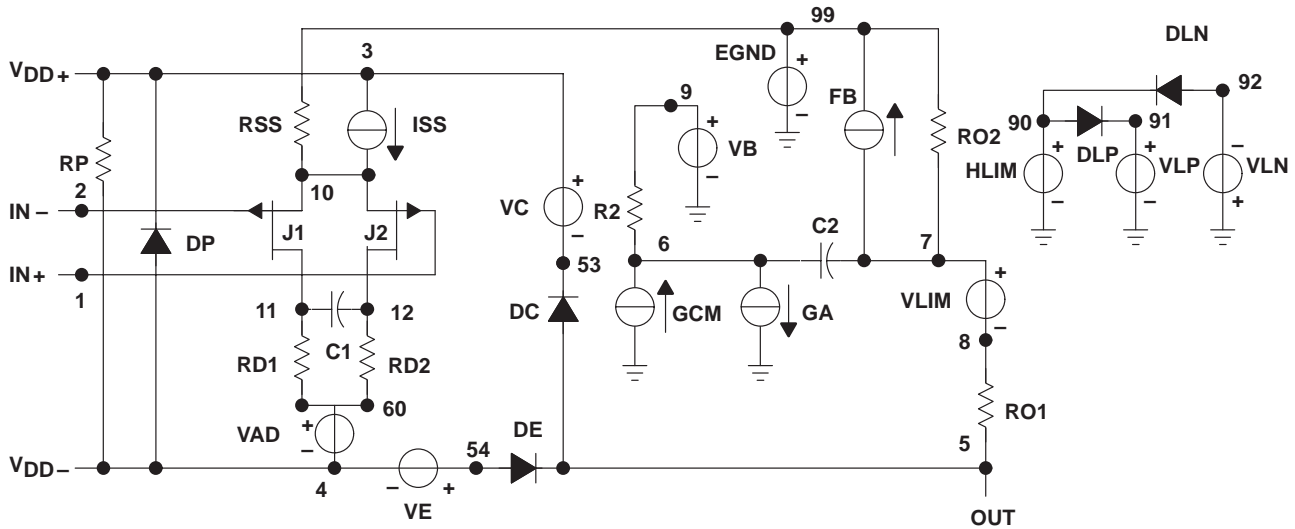
PSpice and *Parts* are trademarks of MicroSim Corporation.



TLV2470, TLV2471, TLV2472, TLV2473, TLV2474, TLV2475, TLV247xA
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APPLICATION INFORMATION



* AMP_TLV2470-X operational amplifier "macromodel" subcircuit
 * created using Parts release 8.0 on 10/12/98 at 11:06
 * Parts is a MicroSim product.

* connections: non-inverting input
 * | inverting input
 * | positive power supply
 * | negative power supply
 * | output
 *
 .subckt AMP_TLV2470-X 1 2 3 4 5

c1	11	12	1.1094E-12
c2	6	7	5.5000E-12
css	10	99	556.53E-15
dc	5	53	dy
de	54	5	dy
dlp	90	91	dx
dln	92	90	dx
dp	4	3	dx
egnd	99	0	poly(2) (3,0) (4,0) 0 .5 .5
fb	7	99	poly(5) vb vc ve vlp vln 0
+ 39.614E6 -1E3 1E3 40E6 -40E6			
ga	6	0	11 12 79.828E-6
gcm	0	6	10 99 32.483E-9

iss	10	4	dc	10.714E-6
hlim	90	0	vlim	1K
ioff	0	6	dc	75E-9
j1	11	2	10	jx1
j2	12	1	10	jx2
r2	6	9	100.00E3	
rd1	3	11	12.527E3	
rd2	3	12	12.527E3	
ro1	8	5	10	
ro2	7	99	10	
rp	3	4	3.8023E3	
rss	10	99	18.667E6	
vb	9	0	dc	0
vc	3	53	dc	.842
ve	54	4	dc	.842
vlim	7	8	dc	0
vlp	91	0	dc	110
vln	0	92	dc	110
.model dx D(Is=800.00E-18)				
.model dy D(Is=800.00E-18 Rs=1m Cjo=10p)				
.model jx1 NJF(Is=1.0825E-12 Beta=594.78E-06				
+ Vto=-1)				
.model jx2 NPN(Is=1.0825E-12 Beta=594.78E-06				
+ Vto=-1)				
.ends				

* Schematics Subcircuit *
 .subckt TLV2470_ver1 Vout Vdd GND V+ V- SD

```
S_S2 $N_0001 GND SD GND S2
RS_S2 SD GND 1G
.MODEL S2 VSWITCH Roff=1e6 Ron=1.0 Voff=0.0
+ Von=1.0
S_S1 $N_0002 VDD SD GND S1
RS_S1 SD GND 1G
.MODEL S1 VSWITCH Roff=1e6 Ron=1.0 Voff=0.0
+ Von=1.0
S_S3 Vout $N_0003 SD GND S3
RS_S3 SD GND 1G
.MODEL S3 VSWITCH Roff=1e6 Ron=1.0 Voff=0.0
+ Von=1.0
X_SUB_U1 V+ V- $N_0002 $N_003
+ AMP_TLV2470-X
.ENDS TLV2470_ver1
```

* Schematics Subcircuit *
 .subckt TLV2471_ver1 V+ V- Vout Vdd GND

```
X_SUB_U1 V+ V- GND Vout AMP_TLV2470-X
.ENDS TLV2471_ver1
```

Figure 55. Boyle Macromodel and Subcircuit

